

> Features

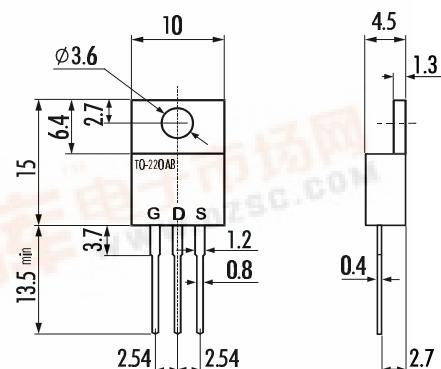
- High Current
- Low On-Resistance
- No Secondary Breakdown
- Low Driving Power
- Avalanche Rated

> Applications

- Motor Control
- General Purpose Power Amplifier
- DC-DC converters

> Outline Drawing

TO-220 AB



> Maximum Ratings and Characteristics

- Absolute Maximum Ratings ($T_C=25^\circ\text{C}$), unless otherwise specified

| Item | Symbol | Rating | Unit |
|---|----------------------|------------|------------------|
| Drain-Source-Voltage | V_{DS} | 60 | V |
| Continous Drain Current | I_D | ± 80 | A |
| Pulsed Drain Current | $I_{D(\text{puls})}$ | ± 320 | A |
| Gate-Source-Voltage | V_{GS} | +30 / -20 | V |
| Maximum Avalanche Energy | E_{AV} | 613 | mJ* |
| Max. Power Dissipation | P_D | 135 | W |
| Operating and Storage Temperature Range | T_{ch} | 150 | $^\circ\text{C}$ |
| | T_{stg} | -55 ~ +150 | $^\circ\text{C}$ |

* $L=0,13\text{mH}$, $V_{CC}=24\text{V}$

- Electrical Characteristics ($T_C=25^\circ\text{C}$), unless otherwise specified

| Item | Symbol | Test conditions | Min. | Typ. | Max. | Unit |
|--|---------------------|--|------|------|-------|------------------|
| Drain-Source Breakdown-Voltage | BV_{DSS} | $I_D=1\text{mA}$ $V_{GS}=0\text{V}$ | 60 | | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $I_D=10\text{mA}$ $V_{DS}=V_{GS}$ | 2,5 | 3,0 | 3,5 | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=60\text{V}$ $T_{ch}=25^\circ\text{C}$ $V_{GS}=0\text{V}$ $T_{ch}=125^\circ\text{C}$ | | 1,0 | 100,0 | μA |
| Gate Source Leakage Current | I_{GSS} | $V_{GS}=\pm 30\text{V}$ $V_{DS}=0\text{V}$ | | 10 | 100 | nA |
| Drain Source On-State Resistance | $R_{DS(on)}$ | $I_D=40\text{A}$ $V_{GS}=10\text{V}$ | | 5,0 | 6,5 | $\text{m}\Omega$ |
| Forward Transconductance | g_{fs} | $I_D=40\text{A}$ $V_{DS}=10\text{V}$ | 25 | 50 | | S |
| Input Capacitance | C_{iss} | $V_{DS}=25\text{V}$ | | 9000 | | pF |
| Output Capacitance | C_{oss} | $V_{GS}=0\text{V}$ | | 1250 | | pF |
| Reverse Transfer Capacitance | C_{rss} | $f=1\text{MHz}$ | | 700 | | pF |
| Turn-On-Time t_{on} ($t_{on}=t_{d(on)}+t_r$) | $t_{d(on)}$ | $V_{CC}=30\text{V}$ | | 50 | | ns |
| | t_r | $V_{GS}=10\text{V}$ | | 200 | | ns |
| Turn-Off-Time t_{off} ($t_{off}=t_{d(off)}+t_f$) | $t_{d(off)}$ | $I_D=80\text{A}$ | | 150 | | ns |
| | t_f | $R_{GS}=10\Omega$ | | 135 | | ns |
| Avalanche Capability | I_{AV} | $L=100\mu\text{H}$ $T_{ch}=25^\circ\text{C}$ | 80 | | | A |
| Diode Forward On-Voltage | V_{SD} | $I_F=80\text{A}$ $V_{GS}=0\text{V}$ $T_{ch}=25^\circ\text{C}$ | | 1,0 | 1,5 | V |
| Reverse Recovery Time | t_{rr} | $I_F=50\text{A}$ $V_{GS}=0\text{V}$ | | 85 | | ns |
| Reverse Recovery Charge | Q_{rr} | $-dI_F/dt=100\text{A}/\mu\text{s}$ $T_{ch}=25^\circ\text{C}$ | | 0,25 | | μC |

- Thermal Characteristics

| Item | Symbol | Test conditions | Min. | Typ. | Max. | Unit |
|--------------------|----------------|--------------------|------|------|-------|--------------------|
| Thermal Resistance | $R_{th(ch-a)}$ | channel to ambient | | | 75,0 | $^\circ\text{C/W}$ |
| | $R_{th(ch-c)}$ | channel to case | | | 0,926 | $^\circ\text{C/W}$ |

N-channel MOS-FET

60V 6,5mΩ ±80A 135W

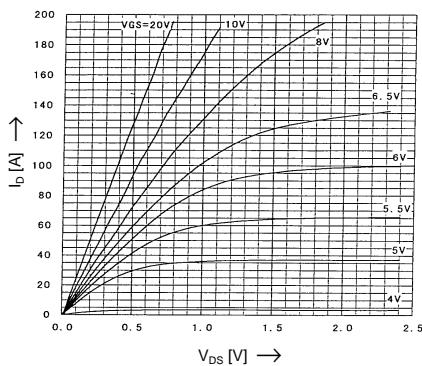
2SK3270-01

Trench Gate MOSFET

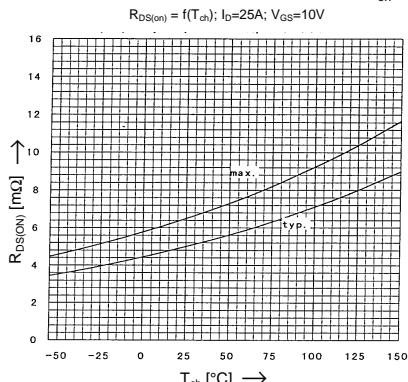
FUJI
ELECTRIC

> Characteristics

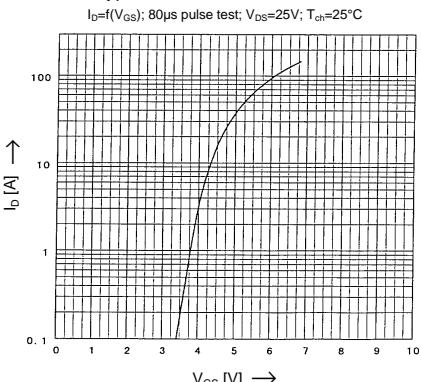
Typical Output Characteristics
 $I_D = f(V_{DS})$; 80μs pulse test; $T_C = 25^\circ C$



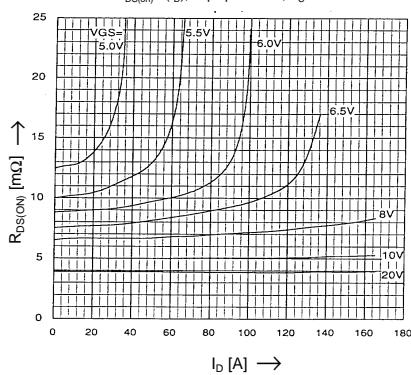
Drain-Source On-State Resistance vs. T_{ch}



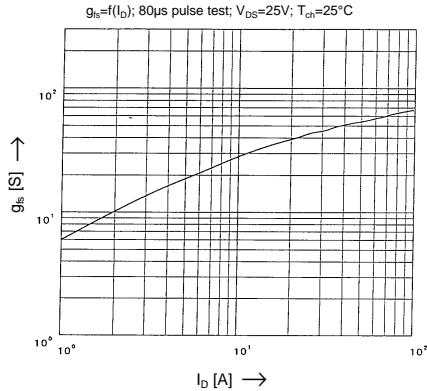
Typical Transfer Characteristics



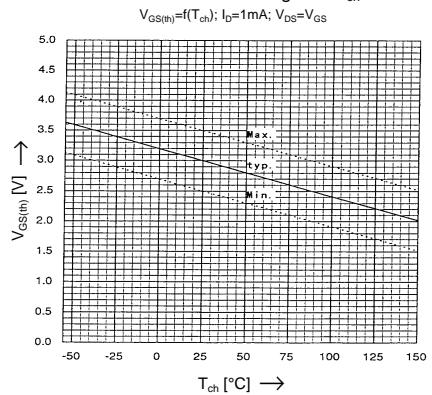
Typical Drain-Source On-State-Resistance vs. I_D
 $R_{DS(on)} = f(I_D)$; 80μs pulse test; $T_C = 25^\circ C$



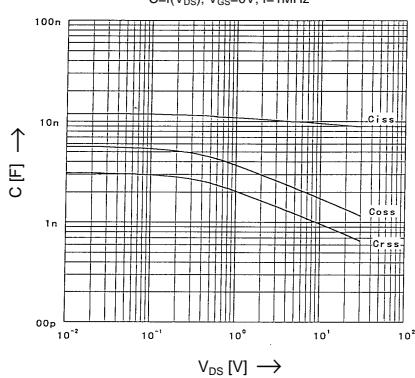
Typical Forward Transconductance vs. I_D



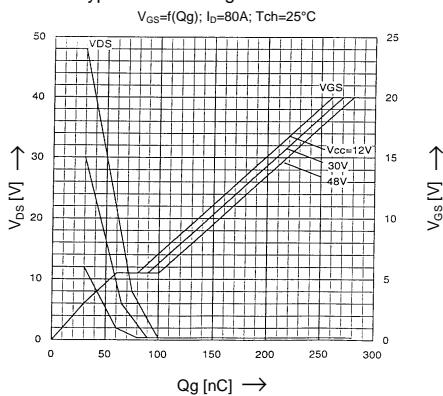
Gate Threshold Voltage vs. T_{ch}



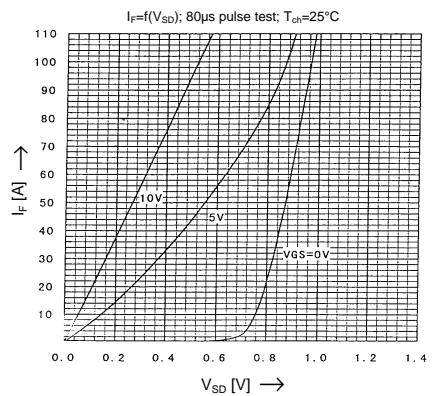
Typical Capacitances vs. V_{DS}
 $C = f(V_{DS})$; $V_{GS} = 0V$; $f = 1MHz$



Typical Gate Charge Characteristic

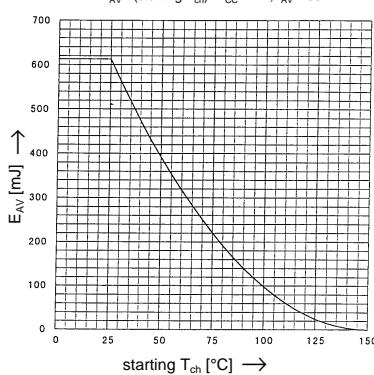


Forward Characteristics of Reverse Diode

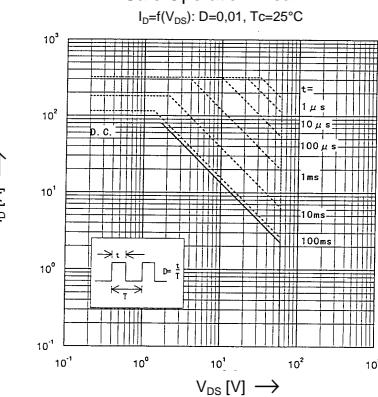


Maximum Avalanche Energy vs. starting T_{ch}

$E_{AV} = f(\text{starting } T_{ch})$; $V_{CC} = 24V$; $I_{AV} \leq 80A$



Safe Operation Area



Transient Thermal impedance

